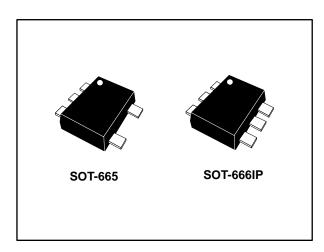


ESDALC6V1Px

Low capacitance Transil[™] arrays for ESD protection

Datasheet - production data



Features

- 2 to 4 unidirectional Transil functions
- Breakdown voltage V_{BR} = 6.1 V min
- Low leakage current < 100 nA
- Low diode capacitance (7.5 pF at 3 V)
- Very small PCB area < 2.6 mm²

Benefits

- High ESD protection level
- High integration

Complies with the following standards

- IEC 61000-4-2 (exceeds level 4)
 - 20 kV (air discharge)
 - 8 kV (contact discharge)
- MIL STD 883E Method 3015-7: class 3
 - 25 kV HBM (human body model)

Applications

Where transient overvoltage protection in ESD sensitive equipment is required, such as:

- Automotive applications
- Computers
- Printers
- Communication systems
- Cellular phone handsets and accessories
- Wireline and wireless telephone sets
- Set-top boxes

Description

These devices are monolithic suppressors designed to protect components connected to data and transmission lines against ESD. They clamp the voltage just above the logic level supply for positive transients and to a diode drop below ground for negative transients.

Figure 1: ESDALC6V1P5 functional diagram

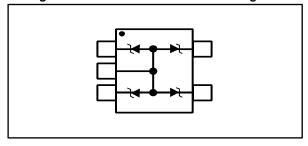
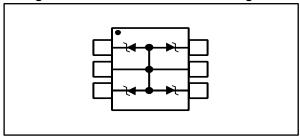


Figure 2: ESDALC6V1P6 functional diagram





TM: Transil is a trademark of STMicroelectronics

August 2017 DocID12636 Rev 8 1/11

Characteristics ESDALC6V1Px

1 Characteristics

Table 1: Absolute maximum ratings (T_{amb} = 25 °C)

Symbol		Value	Unit	
		IEC 61000-4-2:		
V _{PP}	Peak pulse voltage	Contact discharge	8	1.37
		Air discharge	20	kV
		MIL STD 883G - method 3015-7: Class3	25	
P _{PP}	Peak pulse power 8/20µs, T _j initial = T _{amb}		30	W
T _{stg}	Storage temperature i	-55 to +150		
Tj	Junction temperature	150	°C	
T∟	Maximum lead tempe	260		
T _{op}	Operating temperature	-40 to +150		

Figure 3: Electrical characteristics (definitions)

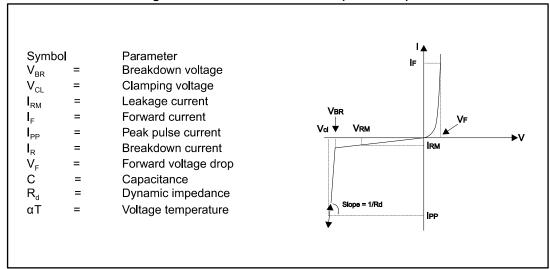


Table 2: Electrical characteristics (T_{amb} = 25 °C)

	V _{BR} at I _R		I _{RM} at V _{RM}			Rd	αΤ	С	
Order code	Min.	Max.		Тур.	Max.		Тур.	Тур.	Typ. at 3 V
	٧	٧	mA	nA	μΑ	٧	Ω	10 ⁻⁴ /°C	pF
ESDALC6V1P5 ESDALC6V1P6	6.1	7.2	1	10	0.1	3	1.5	4.5	7.5

ESDALC6V1Px Characteristics

1.1 Characteristics (curves)

0

25

Figure 4: Peak pulse power dissipation versus initial junction temperature

PPP[Tj initial] / PPP[Tj initial = 25 °C]

1.1

0.9

0.8

0.7

0.6

0.5

0.4

0.3

0.2

0.1

0.0

100

Figure 5: Peak pulse power versus exponential pulse duration (T_j initial = 25 °C)

PPP(W)

Tylinital = 25 °C

100

tp(µs)

101

102

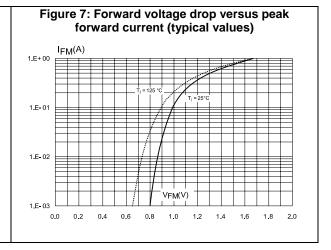


Figure 8: Junction capacitance versus reverse applied voltage (typical values)

C(pF)

C(pF)

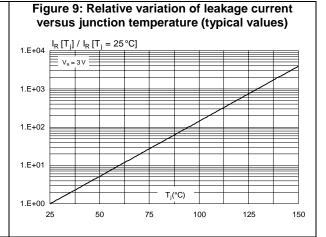
F=1MHz
Vose=30 mV_{RMS}
T_j=28 °C

N

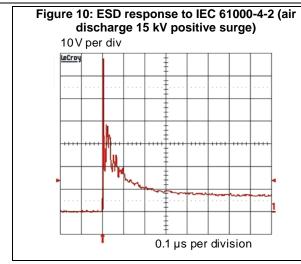
O

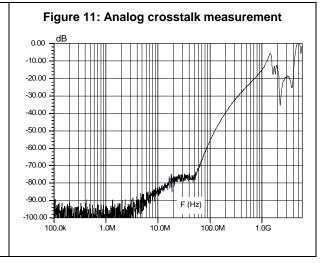
O

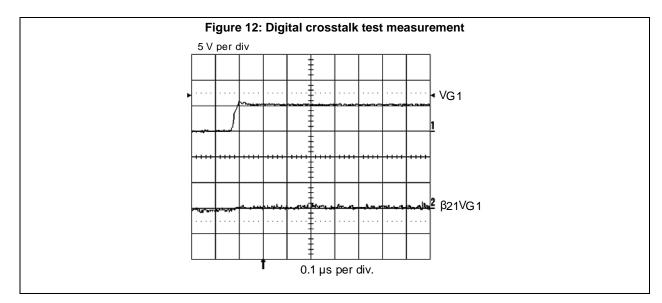
1 2 3 4 5 6



Characteristics ESDALC6V1Px







ESDALC6V1Px Package information

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

2.1 SOT-665 package information

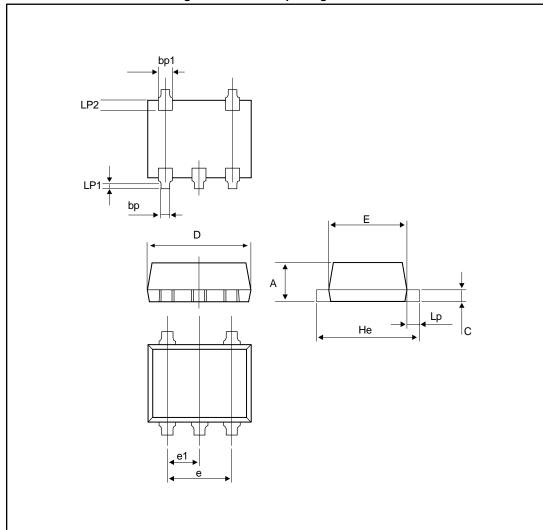
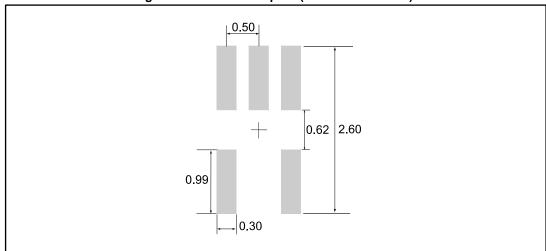


Figure 13: SOT-665 package outline

Table 3: SOT-665 package mechanical data

rable 3. 301-003 package mechanical data									
	Dimensions								
Ref.		Millimeters		Inches					
	Min.	Тур.	Max.	Min.	Тур.	Max.			
Α	0.5		0.62	0.020		0.024			
bp	0.17		0.27	0.007		0.011			
bp1	0.27		0.34	0.011		0.013			
С	0.08		0.18	0.003		0.007			
D	1.5		1.7	0.060		0.067			
Е	1.1		1.3	0.043		0.051			
е		1			0.039				
e1		0.5			0.020				
He	1.5		1.7	0.059		0.067			
Lp	0.1		0.3	0.004		0.012			
Lp1	0.1	0.05		0.004	0.002				
Lp2	0.11		0.26	0.004		0.010			

Figure 14: SOT-665 footprint (dimensions in mm)



ESDALC6V1Px Package information

2.2 SOT-666IP package information

Figure 15: SOT-666IP package outline

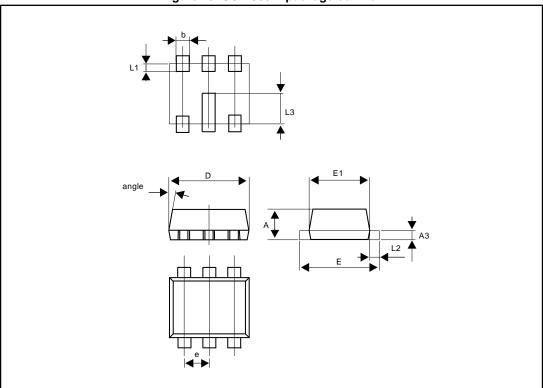
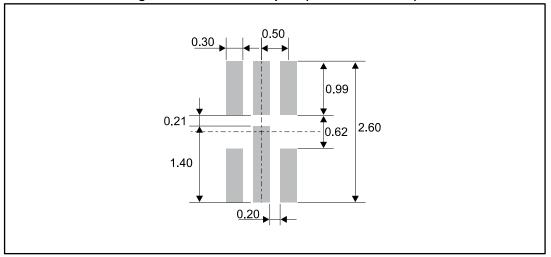


Table 4: SOT-666IP package mechanical data

	Dimensions									
Ref.		Millimeters		Inches						
	Min.	Тур.	Max.	Min.	Тур.	Max.				
Α	0.45		0.62	0.018		0.024				
А3	0.08		0.18	0.003		0.007				
b	0.17		0.34	0.007		0.0013				
D	1.50		1.70	0.059		0.067				
Е	1.50		1.70	0.059		0.067				
E1	1.10		1.30	0.043		0.051				
е		0.5			0.020					
L1		0.19			0.007					
L2	0.1		0.3	0.004		0.012				
L3		0.6			0.024					

Figure 16: SOT-666IP footprint (dimensions in mm)



ESDALC6V1Px Ordering information

3 Ordering information

Figure 17: Ordering information scheme

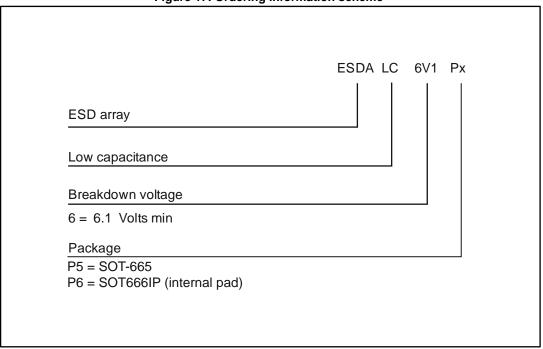


Table 5: Ordering information

Order code Marking ⁽¹⁾		Package	Weight	Base qty.	Delivery mode
ESDALC6V1P5	A1	SOT-665	2.0	2000	Tone and real
ESDALC6V1P6	D	SOT-666IP	2.9 mg	3000	Tape and reel

Notes:

 $[\]ensuremath{^{(1)}}\xspace$ The marking can be rotated by multiples of 90° to differentiate assembly location

Revision history ESDALC6V1Px

Revision history 4

Table 6: Document revision history

Date	Revision	Changes
16-Aug-2006	1	ESDALC6V1P3, ESDALC6V1P5, and ESDALC6V1P6 merged and reformatted to current standards.
23-Aug-2006	2	Table 1 on page 2: Temperature range upgraded to T _j max = 150 °C
11-Oct-2006	3	Added values for VPP in Table 1.
23-Apr-2008	4	Reformatted to current standards. Added I _{RM} typical value in <i>Table 2.</i> Update minimum dimension for L2 of SOT-663 in <i>Table 3.</i>
15-Jan-2010	5	Updated Figure 17: SOT-665 footprint (dimensions in mm).
03-Dec-2014	6	Updated SOT-666IP dimension definitions and reformatted to current standard.
		Removed SOT-663 package.
17-Mar-2017	7	Updated Table 1: "Absolute maximum ratings (Tamb = 25 °C)".
		Updated <i>Table 3:</i> "SOT-665 package mechanical data" and <i>Table 3:</i> "SOT-665 package mechanical data".
03-Aug-2017	8	Updated Section 2.1: "SOT-665 package information".

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